

# Low Temperature Crystallization of Dust

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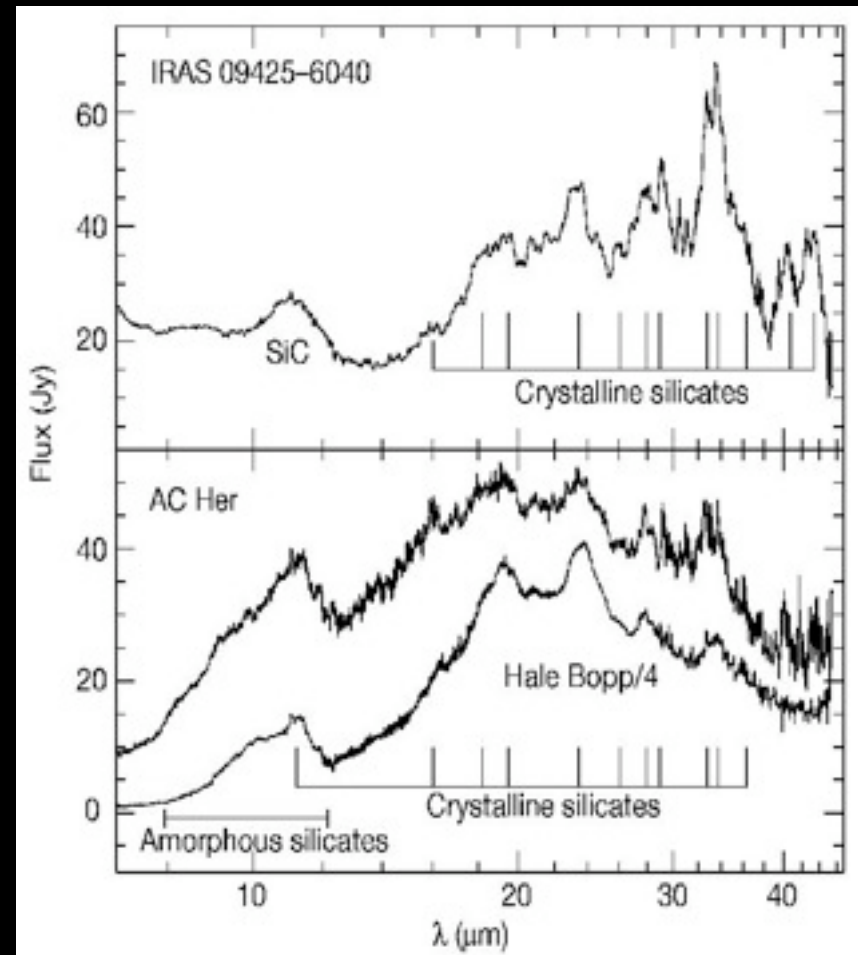
(Tanaka+2010, ApJ, 717, 586)

Staub in Planetensystemen/惑星系の「うちゅうじん」

Japanese-German Workshop  
September 27-October 01, 2010

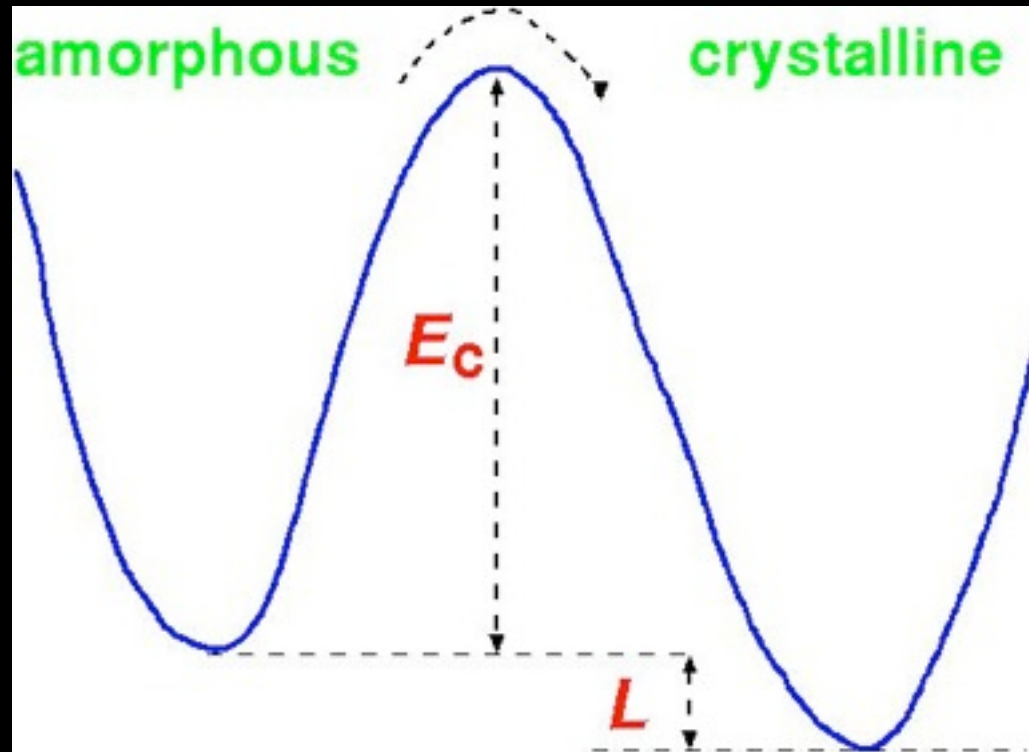
# Crystalline silicate in various kinds of objects

- Observed in
  - evolved stars
    - C-rich giant stars, post AGB stars
  - Herbig Ae/Be stars
  - T Tauri stars
  - young MS stars
  - Comets
  - ZL dust
  - IDPs
  - other galaxies (ULIRG)
- Not observed in
  - ISM & molecular clouds
  - Protostars



(Molster et al. 1999)

# Crystallization: Transition from amorphous to crystalline state



internal energy :  $E(\text{crystal}) < E(\text{amorphous})$

- $L$  : latent heat of crystallization
- must overcome energy barrier  $E_c$  for crystallization

# Energy source to overcome $E_c$

## Annealing induced by fluctuation of thermal energy

(Hallenbeck et al. 1998, Fabian et al. 2000, Kamitsuji et al. 2005,  
and many others)

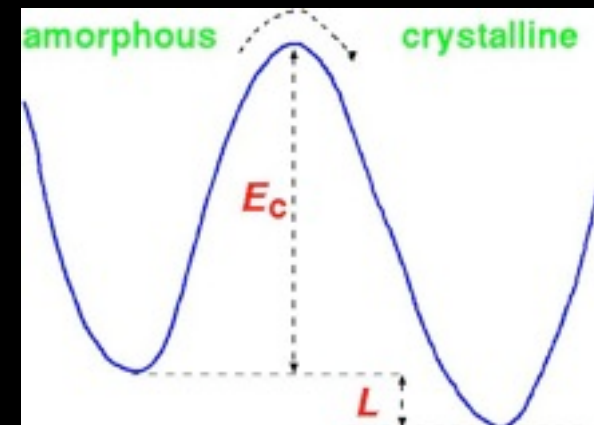
### But other energy sources:

- irradiation of electrons or high energy particles

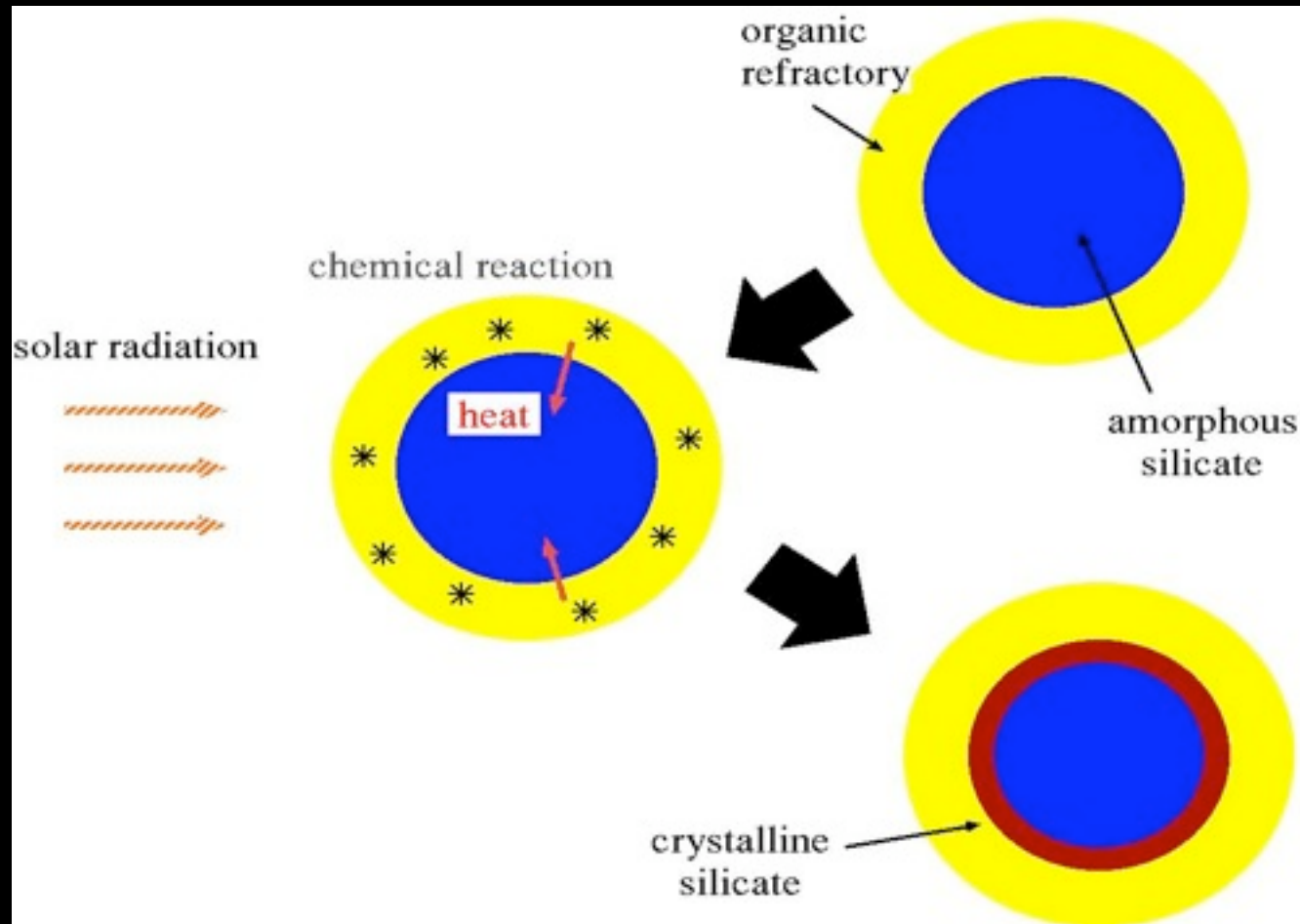
(Carrez et al. 2002, Y. Kimura et al. 2008)

- heat of chemical reactions

(Yamamoto & Chigai 2005, Yamamoto+2010)



# Basic idea of crystallization by heat of reactions

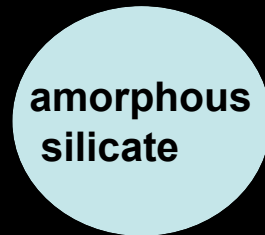


- 0) Suppose a silicate grain coated with a mantle including chemically reactive molecules (radicals).
  - 1) Moderate heating induces chemical reactions in the mantle
  - 2) heat of reactions leads to crystallization

(Yamamoto & Chigai 2005, Yamamoto+2010)

# Series of experiments by Kaito et al. (Kamitsuji et al. 2005; Kaito et al. 2007a,b)

Exp.1



amorphous  
silicate

→  
 $T \sim 1000\text{K}$

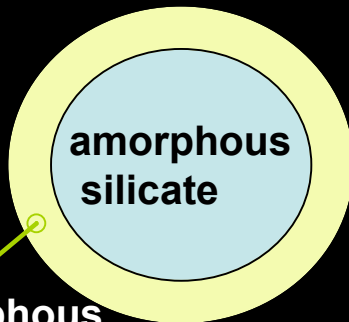


forsterite

↔  
 $\sim 100\text{nm}$

heating  
in vacuum

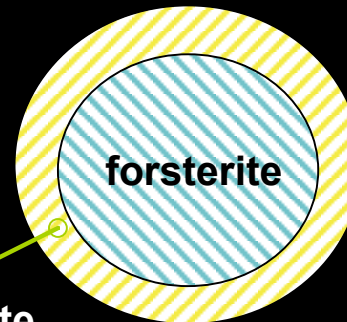
Exp.2



amorphous  
silicate

amorphous  
carbon

→  
 $T \sim 870\text{K}$

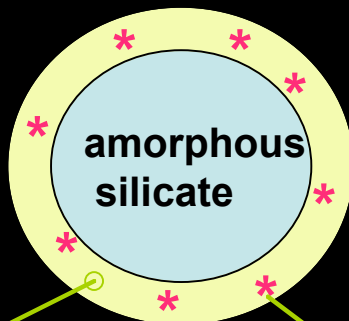


forsterite

graphite

heating  
in vacuum

Exp.3

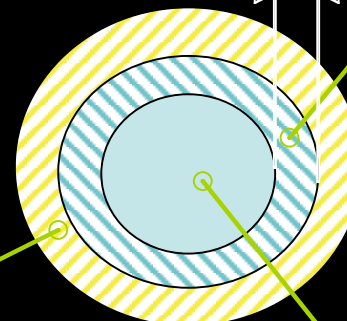


amorphous  
silicate

amorphous  
carbon

CH<sub>4</sub>

→  
 $T \sim 300\text{K}$



forsterite

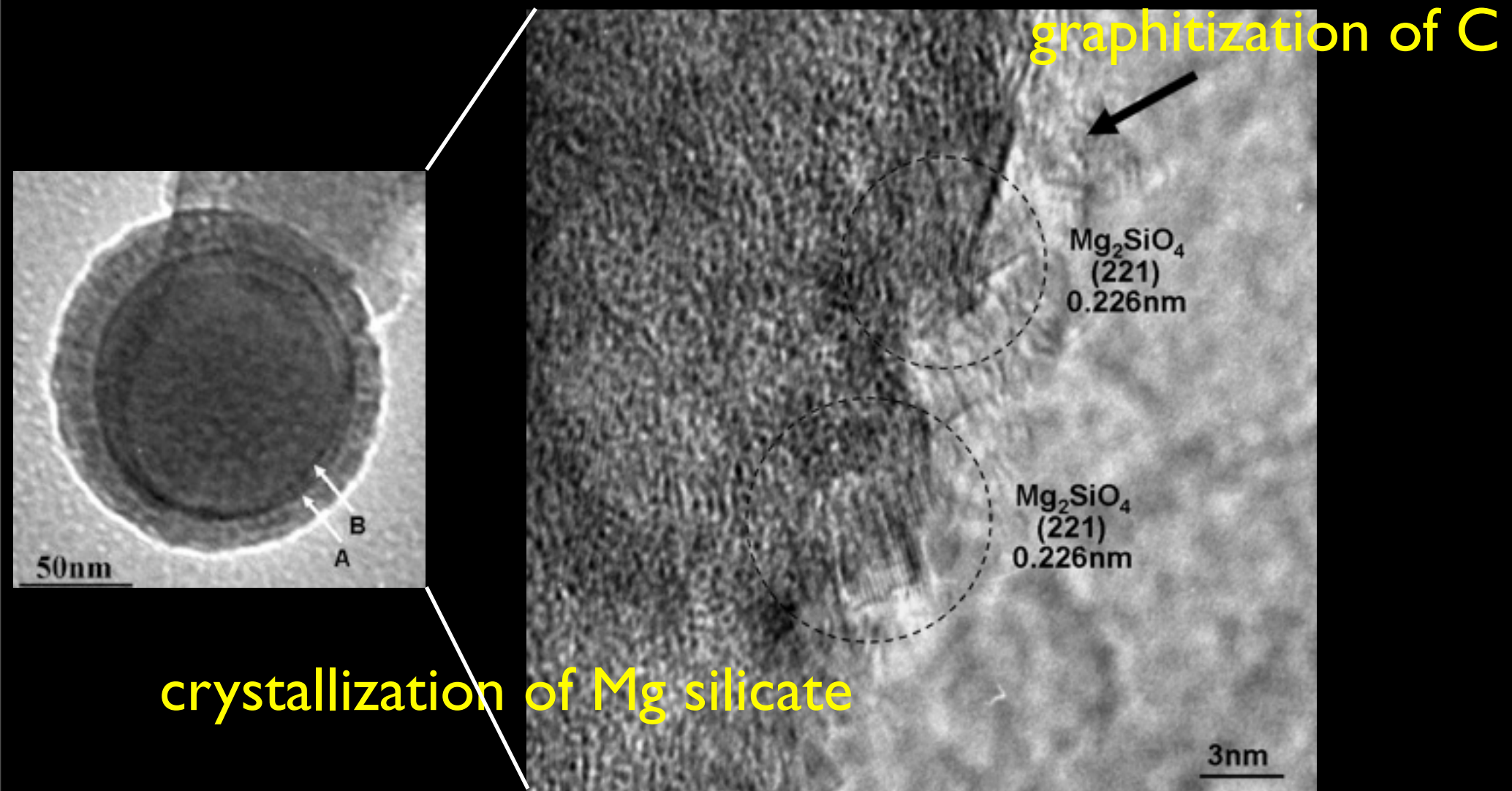
graphite

amorphous  
silicate

↔  
 $\sim 10\text{nm}$

exposed  
to the air

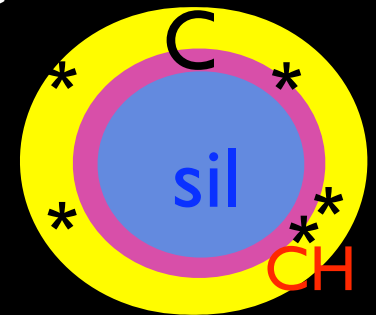
# HREM image of the sample and its magnification of the interface region



Kaito et al. 2007b

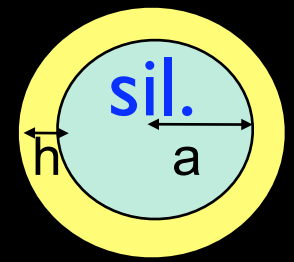
# Picture of crystallization in Exp. 3 by Kaito et al. (2007b)

1. Release of heat of chemical reactions (oxidation of  $\text{CH}_4$ ) in C mantle
2. Induce graphitization in the C mantle
3. Latent heat deposited by graphitization leads further temperature elevation
4. Induce crystallization of silicate from the interface of C mantle and silicate core
5. Cessation of crystallization due to cooling





# Modelling of Exp. 3



organics

Time variation of temperature of the particle

$$\frac{4}{3}\pi a^3 \rho c \frac{dT}{dt} = \frac{4}{3}\pi [(a+h)^3 - a^3] \dot{\epsilon} - \Lambda_{\text{air}} - \Lambda_{\text{rad}} + H_{\text{si}} + H_{\text{c}}$$

Rate of generation of heat of reactions in mantle

$$\dot{\epsilon} = -\frac{dn_{\text{rad}}}{dt} E_{\text{r}} \quad \frac{dn_{\text{rad}}}{dt} = -\nu_{\text{r}} e^{-E_{\text{ar}}/kT} n_{\text{rad}}$$

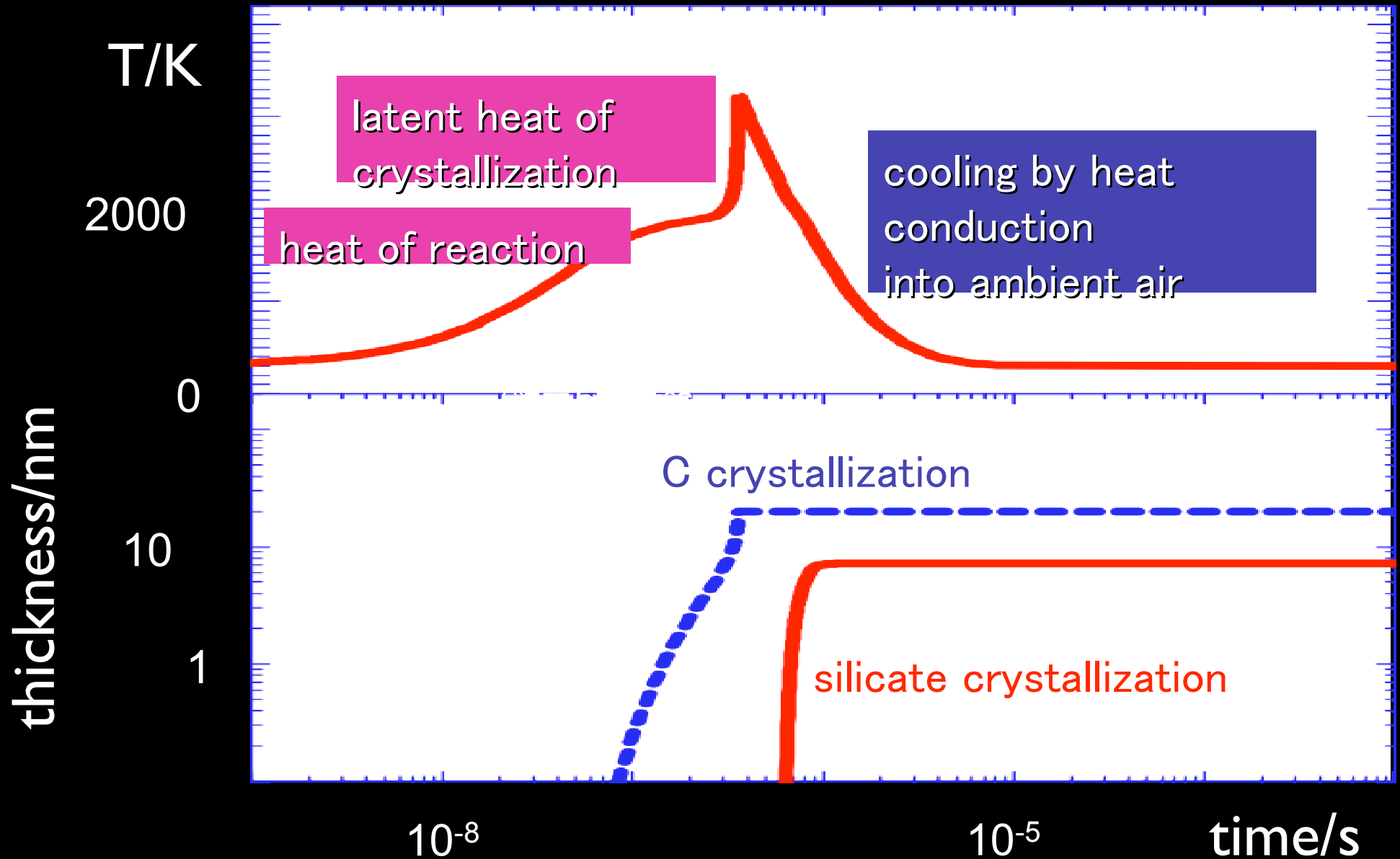
Crystal growth

$$\frac{da_{\text{sil}}}{dt} = a_0 \nu e^{-E_{\text{sil}}/kT} (1 - e^{-q_{\text{sil}}(T_{\text{m}} - T)/kT})$$

# Key physical quantities

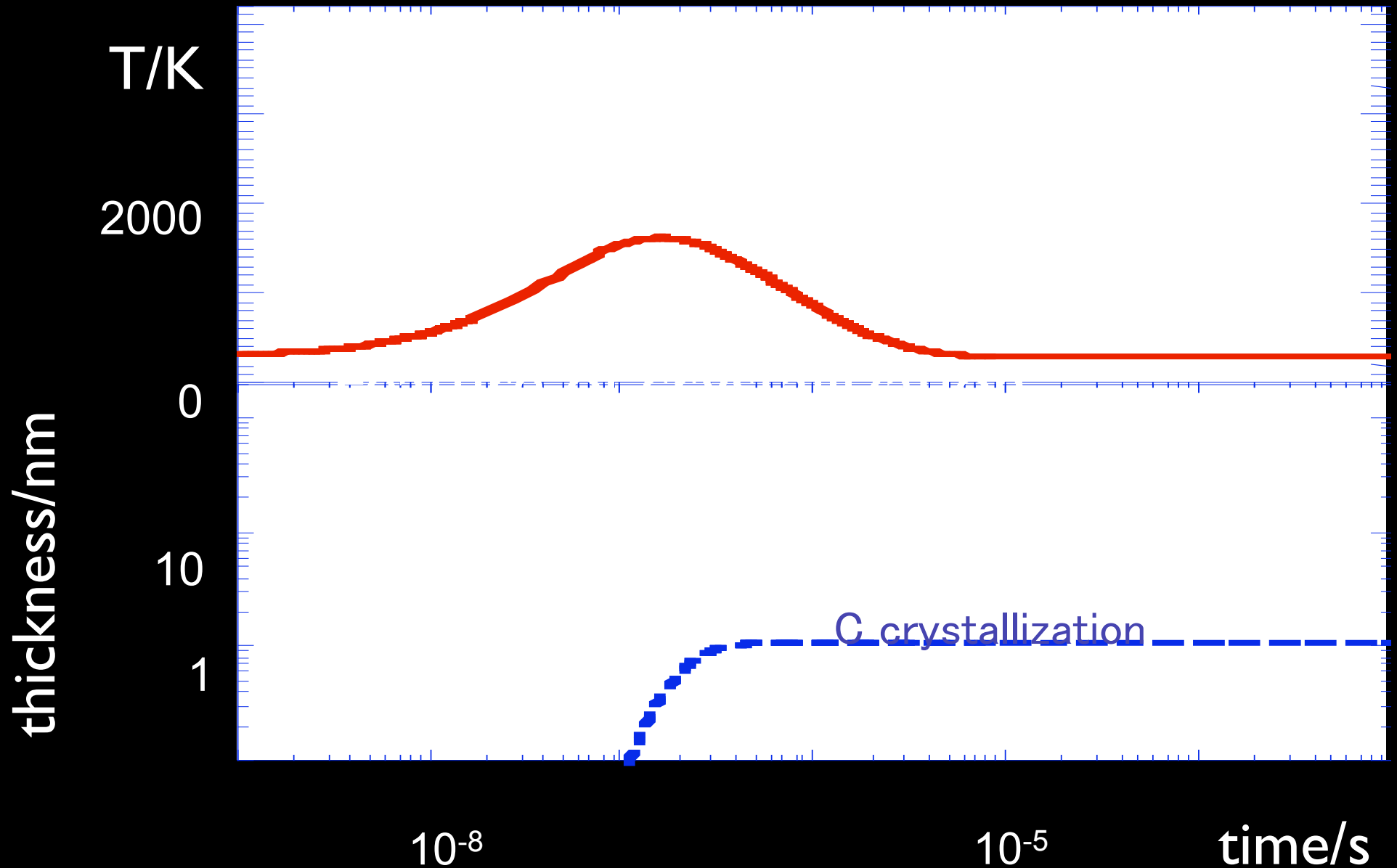
- Stored energy density :  $Q = n_{\text{rad}}(0) E_r$
- Time scale of the reactions :  $\tau$
- Ambient gas pressure

# Feature of crystallization

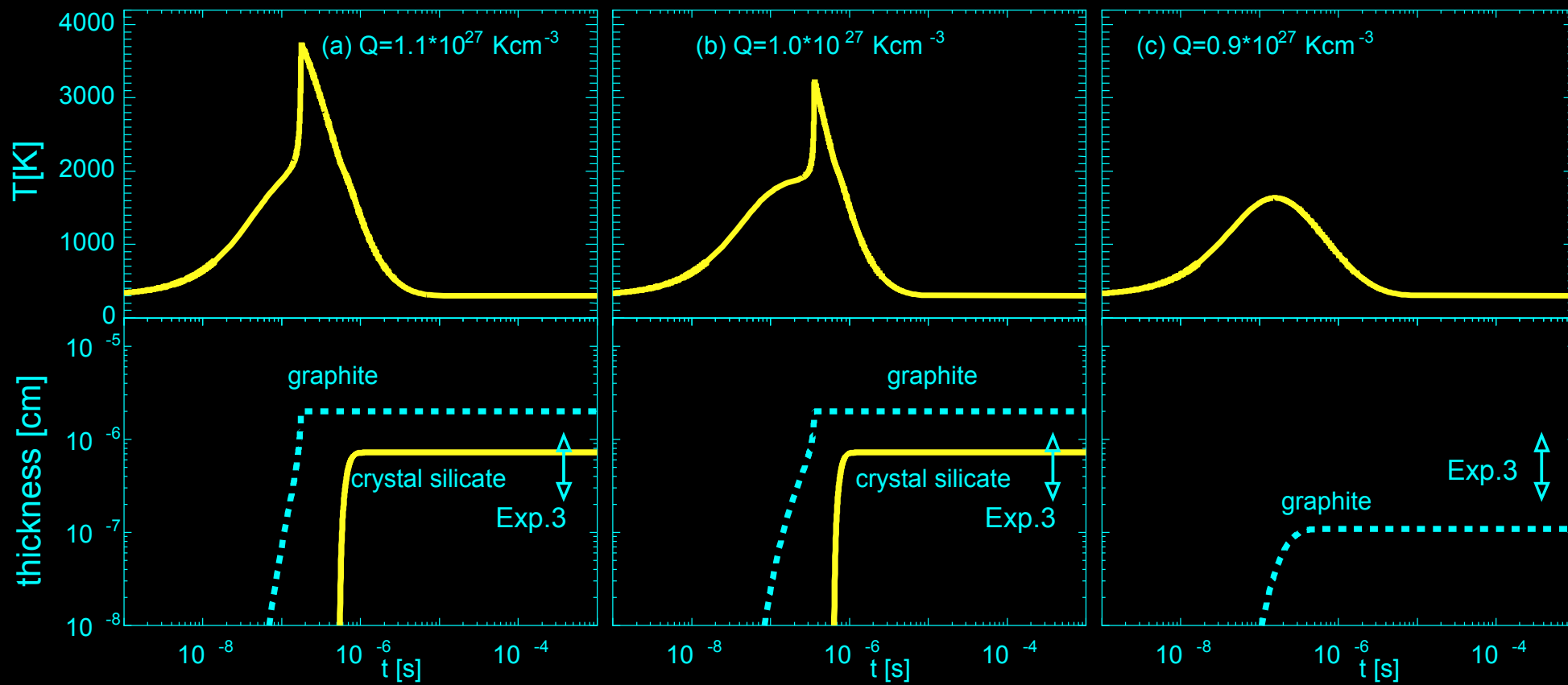


(  $n_{\text{rad}}(0) E_r = 10^{27} \text{ K cm}^{-3}$  ;  $t_r = 10^{-8} \text{ s}$ , gas density =  $10^{-3} \text{ g cm}^{-3} = 1 \text{ atm}$  )

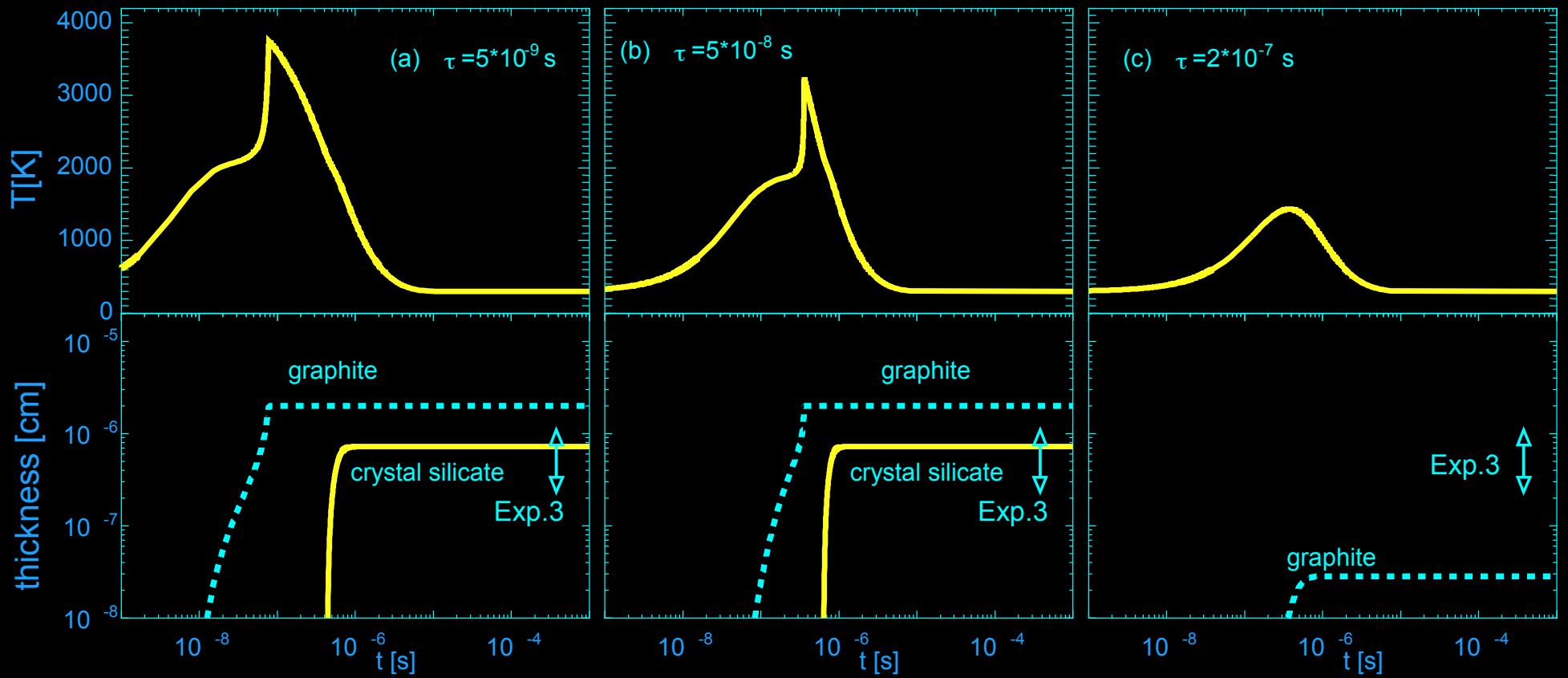
# Feature of crystallization (2) small deposition of heat of reaction



(  $n_{\text{rad}}(0) E_r = 0.9 \times 10^{27} \text{ K cm}^{-3}$ ;  $t_r = 10^{-8} \text{ s}$ , gas density =  $10^{-3} \text{ g cm}^{-3} = 1 \text{ atm}$  )

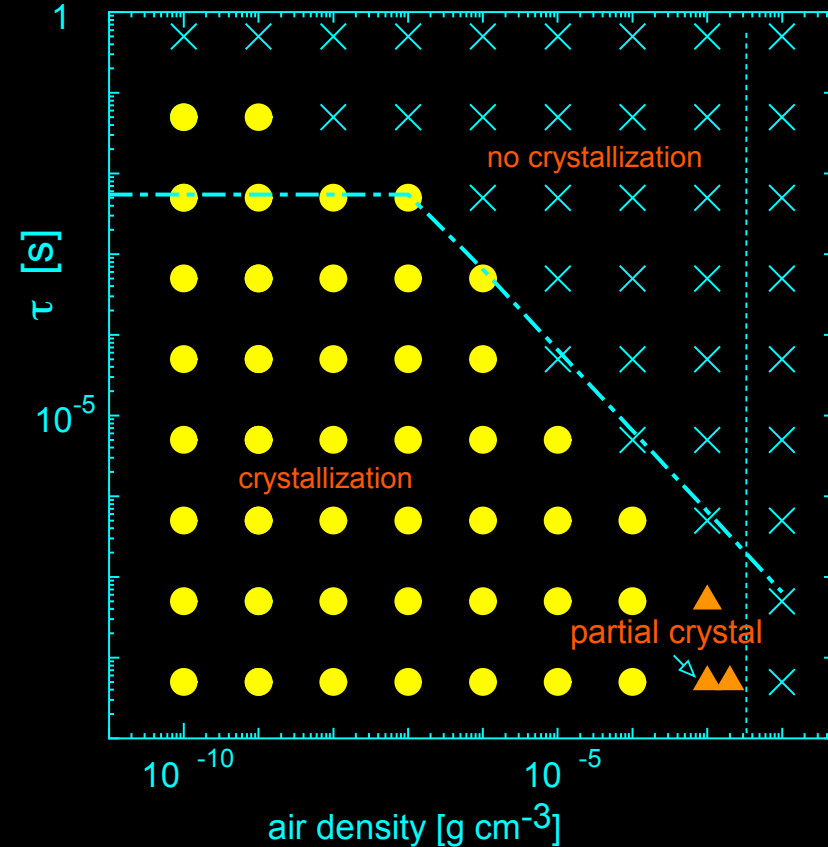
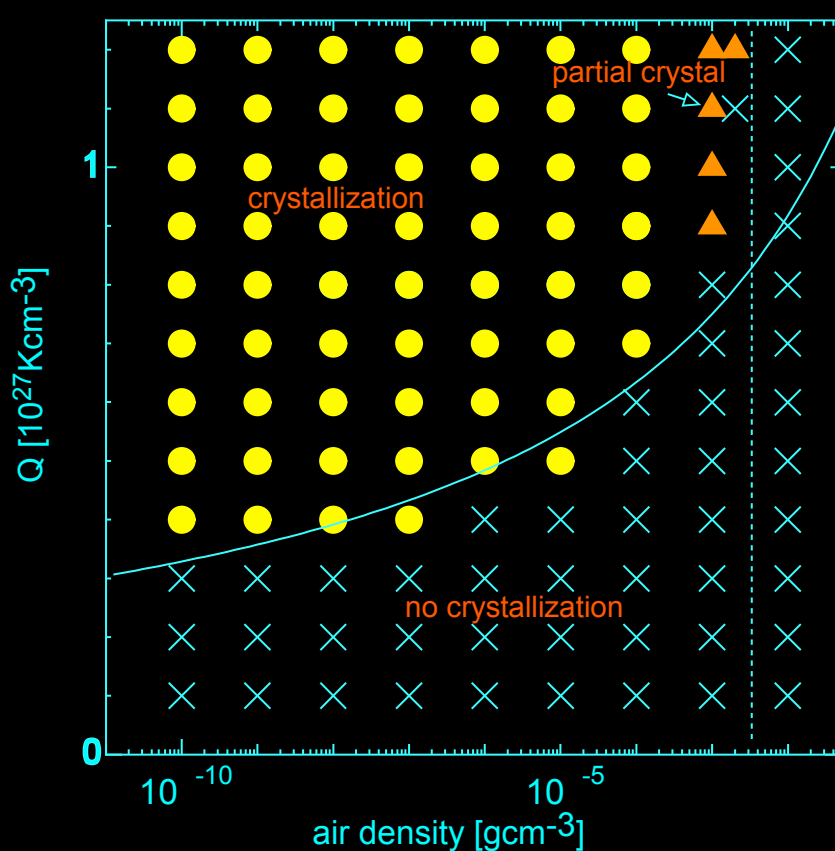


(P = 1 atm)



(P = 1 atm)

# Crystallization conditions

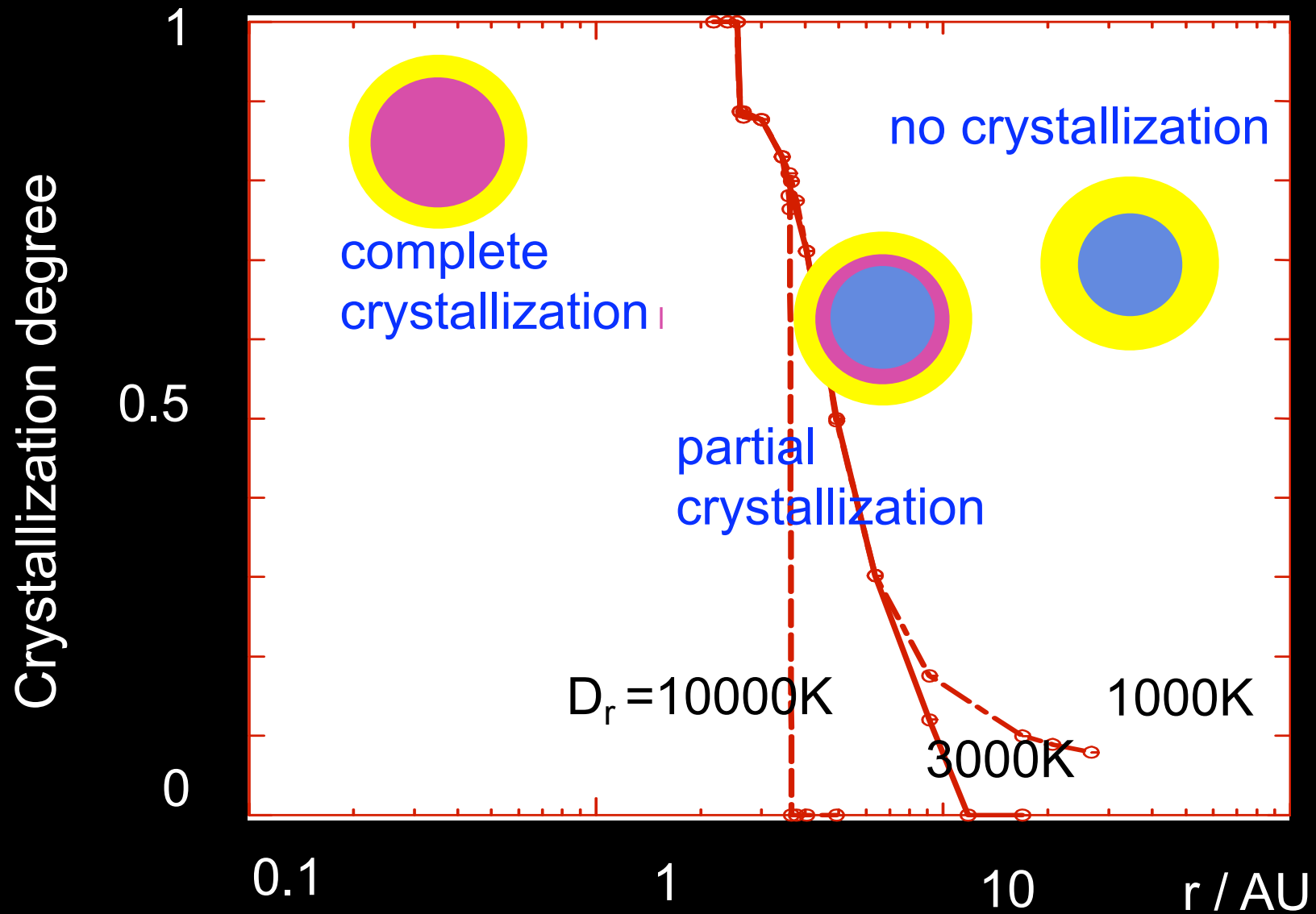


Low gas density, large energy deposition, fast reactions  
➔ easy crystallization

Radical concentration  $> 1 - 10\%$  leads to substantial crystallization

# Crystallization degree in steady accretion disks

$$(Q = n_{\text{rad}}(0) E_r = 10^{27} \text{ K cm}^{-3})$$



Crystalline region is much extended than by annealing.



# Concluding remarks (1/3)

- Crystallization triggered by chemical reactions may explain ubiquity of crystalline silicate in various objects
  - ▶ Similar phenomenon
    - Wigner energy release known in nuclear reactor engineering
    - Sudden release of energy stored in graphite moderator irradiated by neutrons upon moderate heating (Spontaneous energy release)

# Concluding remarks (2/3)

- The present mechanism **does not depend on the details of the chemistry** but depends only on the amount of reactive molecules times heat of reactions,  $Q = n_{\text{rad}}(0) E_r$ , and reaction timescale  $\tau$ .

# Concluding remarks (3/3)

- Similarity of ice compositions in molecular clouds and comets:
  - Present mechanism can explain the **coexistence of crystalline silicate and ice of IS composition in comets** without mixing.
- Search for crystalline silicate at low temperature environments is encouraged by future high resolution observations of disks.